NSN 5962-01-281-5609

Memory Microcircuit - Page 1 of 1

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View Online at https://aerobasegroup.com/nsn/5962-01-281-5609

Body Length:
Between 1.130 inches and 1.260 inches
Body Width:
Between 0.475 inches and 0.530 inches
Body Height:
0.160 inches
Maximum Power Dissipation Rating:
525.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+125.0 degrees celsius
Features Provided:
Electrostatic sensitive and w/enable and hermetically sealed and ultraviolet erasable and programmable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Metal oxide-semiconductor logic
Input Circuit Pattern:
14 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
26.5 volts power source
Time Rating Per Chacteristic:
450.00 nanoseconds propagation delay time, low to high level output and 450.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
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